TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7WG02FC

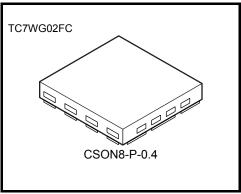
Dual 2-Input NOR Gate

Features

- High-level output current: $I_{OH}/I_{OL} = \pm 8 \text{ mA (min)}$ at V_{CC} = 3 V
- High-speed operation: t_{pd} = 2.8 ns (typ.)

at V_{CC} = 3.3 V,15pF

- Operating voltage range: V_{CC} = 0.9~3.6 V
- 5.5-V tolerant inputs
- 3.6-V power down protection outputs



Weight: 0.002 g (typ.)

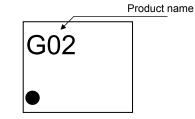
Characteristics	Symbol	Value	Unit
Power supply voltage	V _{CC}	-0.5~4.6	V
DC input voltage	V _{IN}	-0.5~7.0	V
DC output voltage	Varia	-0.5~4.6 (Note 1)	v
DC output voltage	Vout	-0.5~V _{CC} + 0.5 (Note 2)	v
Input diode current	I _{IK}	-20	mA
Output diode current	I _{OK}	-20 (Note 3)	mA
DC output current	I _{OUT}	±25	mA
DC V _{CC} /GND current	ICC	±50	mA
Power dissipation	PD	150 (Note 4)	mW
Storage temperature	T _{stg}	-65~150	°C

Absolute Maximum Ratings (Ta = 25°C)

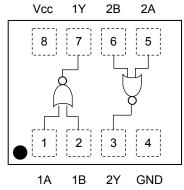
- Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).
- Note 1: $V_{CC} = 0V$
- Note 2: High or Low State.
- I_{OUT} absolute maximum rating must be observed. Note 3: V_{OUT} < GND
- Note 4: Mounted on an FR4 board.

(25.4 mm × 25.4 mm × 1.6 t, Cu Pad: 11.56 mm²)

Marking



Pin Assignment (top view)

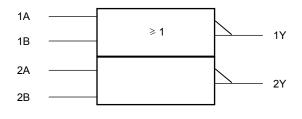


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Truth Table

Inp	uts	Outputs
А	В	Y
L	L	Н
L	Н	L
Н	L	L
Н	Н	L

IEC Logic Symbol



Operating Ranges

Characteristics	Symbol	Value	Unit	
Power supply voltage	V _{CC}	0.9~3.6	V	
Input voltage	V _{IN}	0~5.5	V	
Output voltage	Vau	0~3.6 (Note 5)	V	
	Vout	0~V _{CC} (Note 6)	v	
Output Current	IOH/IOL	±8.0 (Note 7)	mA	
		±4.0 (Note 8)		
		±3.0 (Note 9)		
		±1.7 (Note 10)		
		±0.3 (Note 11)		
		±0.02 (Note 12)		
Operating temperature	T _{opr}	-40~85	°C	
Input rise and fall time	dt/dV	0~10 (Note 13)	ns/V	

Note 5: $V_{CC} = 0V$

Note 6: High or Low state.

Note 7: $V_{CC} = 3.0 \sim 3.6 \text{ V}$

Note 8: $V_{CC} = 2.3 \sim 2.7 \text{ V}$

Note 9: $V_{CC} = 1.65 \sim 1.95 \text{ V}$

Note 10: $V_{CC} = 1.4 \sim 1.6 \text{ V}$

Note 11: $V_{CC} = 1.1 \sim 1.3 \text{ V}$

Note 12: $V_{CC}=0.9\ V$

Note 13: $V_{IN} = 0.8 \sim 2.0 \text{ V}, V_{CC} = 3.0 \text{ V}$

Electrical Characteristics

DC Electrical Characteristics

Characteristics	Symbol	Tost	Condition		Ta = 25°C			Ta = -40~85°C		Unit
Characteristics	Symbol			V _{CC} (V)	Min	Тур.	Max	Min	Max	Onit
				0.9	V _{CC}		_	V _{CC}	—	
				1.1~1.3	V _{CC} × 0.7	_	_	V _{CC} × 0.7	—	
High-level V _{IH} input voltage	1.4~1.6			V _{CC} × 0.65		_	V _{CC} × 0.65	_	V	
	1.65~1.95			$\begin{array}{c} V_{CC} \\ \times \ 0.65 \end{array}$		_	V _{CC} × 0.65	_		
				2.3~2.7	1.7	_		1.7		
				3.0~3.6	2.0	_		2.0		
							GND	—	GND	
Low-level VIL		_			_	$V_{CC} \times 0.3$		V _{CC} × 0.3	V	
						$\begin{array}{c} V_{CC} \\ \times \ 0.35 \end{array}$	_	$\begin{array}{c} V_{CC} \\ \times \ 0.35 \end{array}$		
input voltage				1.65~1.95			V _{CC} × 0.35	_	$\begin{array}{c} V_{CC} \\ \times \ 0.35 \end{array}$	
					_	_	0.7		0.7	
				3.0~3.6	_	_	0.8		0.8	
			I _{OH} =-0.02 mA	0.9	0.75	_		0.75	—	
			I _{OH} = -0.3 mA	1.1~1.3	$\begin{array}{c} V_{CC} \\ \times \ 0.75 \end{array}$	_	_	V _{CC} × 0.75	_	
High-level VOH voltage	$V_{IN} = V_{IL}$	I _{OH} = -1.7 mA	1.4~1.6	$\begin{array}{c} V_{CC} \\ \times \ 0.75 \end{array}$		—	V _{CC} × 0.75	_	V	
		I _{OH} = -3.0 mA	1.65~ 1.95	V _{CC} -0.45		—	V _{CC} -0.45	—		
			I _{OH} = -4.0 mA	2.3~2.7	2.0	_	_	2.0	—	
			I _{OH} = -8.0 mA	3.0~3.6	2.48	_		2.48	_	
		VIN = VIH	I _{OL} = 0.02 mA	0.9	_	_	0.1	—	0.1	V
			I _{OL} = 0.3 mA	1.1~1.3	_	_	$\begin{array}{c} V_{CC} \\ \times \ 0.25 \end{array}$	_	V _{CC} × 0.25	
Low-level V _{OL}	V _{OL}		I _{OL} = 1.7 mA	1.4~1.6			V _{CC} × 0.25	_	$\begin{array}{c} V_{CC} \\ \times \ 0.25 \end{array}$	
	or V _{IL}	I _{OL} = 3.0 mA	1.65~ 1.95			0.45	—	0.45		
			I _{OL} = 4.0 mA	2.3~2.7	_		0.4	_	0.4	
			I _{OL} = 8.0 mA	3.0~3.6	_		0.4	—	0.4	
Input leakage current	I _{IN}	V _{IN} = 0~5.5	V _{IN} = 0~5.5V				±0.1	—	±1.0	μΑ
Power off leakage current	IOFF	V _{IN} = 0~5.5 V _{OUT} = 0~3		0	_	_	1.0	—	10.0	μΑ
Quiescent supply current	Icc	$V_{IN} = V_{CC}$	or GND	3.6	_	_	1.0	_	10.0	μΑ

AC Electrical Characteristics (input $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition		Ta = 25°C Ta = -40~85°C			0~85°C	Unit	
Characteristics	Symbol		V _{CC} (V)	Min	Тур.	Max	Min	Max	Unit
		$C_L = 10 \text{ pF},$ $R_L = 1 \text{ M}\Omega$	0.9		19.8		_	_	ns
			1.1~1.3	_	10.1	18.7	1.0	34.5	
			1.4~1.6		5.9	8.9	1.0	10.8	
			1.65~ 1.95		4.5	6.4	1.0	6.9	
			2.3~2.7		3.1	4.2	1.0	4.7	
			3.0~3.6		2.3	3.4	1.0	4.0	
	^t pLH tpHL	C _L = 15 pF, R _L = 1 MΩ	0.9		22.5			_	
			1.1~1.3		11.6	21.5	1.0	37.2	
Propagation delay time			1.4~1.6		6.6	9.8	1.0	12.0	
			1.65~ 1.95		5.0	7.1	1.0	7.3	
			2.3~2.7		3.5	4.5	1.0	5.1	
			3.0~3.6		2.8	3.8	1.0	4.4	
		$C_L = 30 \text{ pF},$ $R_L = 1 \text{ M}\Omega$	0.9		30.0		_	_	
			1.1~1.3		15.0	29.6	1.0	56.0	
			1.4~1.6		8.5	13.1	1.0	15.9	
			1.65~ 1.95		6.3	9.2	1.0	9.6	
			2.3~2.7		4.3	5.7	1.0	6.1	
			3.0~3.6		3.5	4.4	1.0	4.8	
Input capacitance	C _{IN}		3.6	_	3				pF
Power dissipation capacitance	C _{PD}	(Note 14)	0.9 ~ 3.6		11	_	_		pF

Note 14:C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

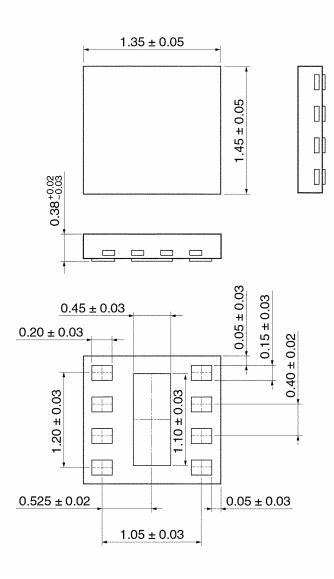
Average operating current can be obtained by the equation:

 $I_{CC \text{ (opr.)}} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/2$

TOSHIBA

Package Dimensions

CSON8-P-0.4



Weight: 0.002 g (typ.)

Unit: mm

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20070701-EN GENERAL

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